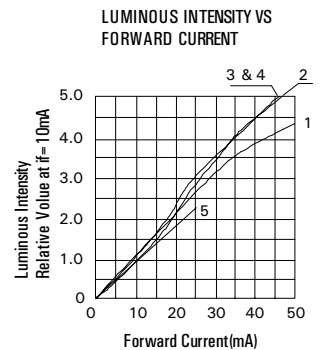
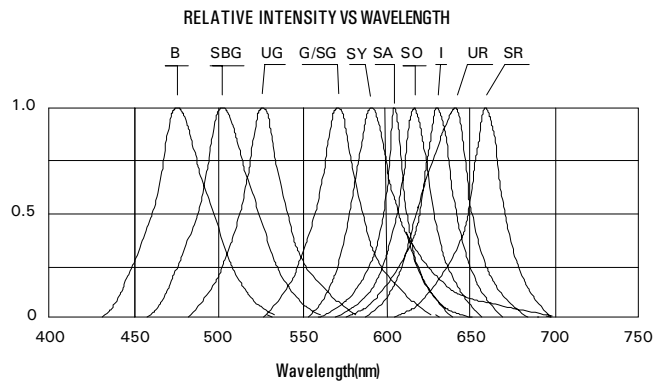
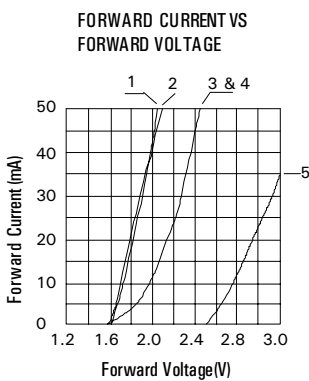


Face Length	MM	10.0
Face Width	MM	10.0
Height	MM	6.2
Pin Spacing	MM	2.5
Row Spacing	MM	7.6
No. of pins	Pins	8

Note : All Dimensions are in mm
Tolerance ± 0.2 mm

PART NO.			KLLB1010 I	KLLB1010 SR	KLLB1010 G	KLLB1010 SG	KLLB1010 SY	KLLB1010 SA	KLLB1010 UR	KLLB1010 SO	KLLB1010 B/UB	KLLB1010 BG	KLLB1010 UG	KLLB1010 W		
OPERATING CHARACTERISTICS AT 25°C (Bigger Display may have more than one LED chip per segment)			UNITS	SYMBOL	IRE D I	SUPER RED SR	GREEN G	SUPER GREEN SG	SUPER YELLOW SY	SUPER AMBER SA	ULTRA RED UR	SUPER ORANGE SO	BLUE B/UB	BLUE GREEN BG	ULTRA GREEN UG	WHITE W
Semiconductor Composition					AlGaAs		GaP/AlInGaP		AllnGaP			SiC / GaInN				
Forward Voltage - Typical @ 10mA			V	V_F	2.10	1.90	2.20	2.20	2.10	2.10	1.90	1.90	3.50	3.50	3.50	3.50
Forward Voltage - Maximum @ 20 mA			V	V_{FM}	2.40	2.10	2.60	2.40	2.40	2.40	2.10	2.40	4.50	4.50	4.50	4.50
Reverse Current @ $V_R = 5V$			μA	I_R	100	100	100	100	100	100	100	100	100	100	100	100
Peak Emission Wavelength			nm	λ_p	630	660	568	568	590	610	645	620	470	502	525	---
Emission Wavelength Half Width			nm	Δ_λ	35	20	30	15	15	15	20	20	25	30	35	---
Luminous Intensity per Segment			μcd	I_V	3500	6000	4000	6000	7000	7500	13000	13000	6000	7000	17000	---
ABSOLUTE MAXIMUM RATINGS AT 25°C																
Reverse Voltage			V	V_R	5	5	5	5	5	5	5	5	5	5	5	5
Forward Current (avg)			mA	I_F	20	20	20	20	20	20	20	20	20	20	20	20
Peak Forward Current ($T < 1\mu s$)			mA	I_{FS}	80	80	80	80	80	80	80	80	80	80	80	80
Operating / Storage Temperature Range			-10° C to + 85° C													
Lead Soldering Temperature			< 260° C for 5 Seconds													
Series Resistor to be used per segment : 300 Ohms @ 5V Supply (OR) 50 to 100 Ohms @ 3V Supply																

ELECTRICAL CHARACTERISTIC CURVES



1. AlGaAs : I, SR

2. GaP : G

3 & 4. AllnGaP : SG, SY, SA, UR, SO

5. GaInN : B, BG, UG, W